

HMC533LP4E

Data Sheet

MMIC VCO w/ DIVIDE-BY-16, 23.8 - 24.8 GHz

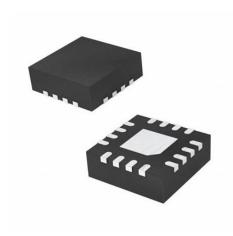
Manufacturers Analog Devices, Inc

Package/Case 24-VFQFN

Product Type RF Integrated Circuits

RoHS Pb-free Halide free

Lifecycle



Images are for reference only

Please submit RFQ for HMC533LP4E or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

The HMC533LP4(E) are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC533LP4(E) integrate resonators, negative resistance devices, varactor diodes and feature a divide-by-16 output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +12 dBm typical from a +5V supply voltage. Prescaler function can be disabled to conserve current if not required. The voltage controlled oscillator is packaged in a leadless QFN 4x4 mm surface mount package.

Features Application

Pout: +12 dBm VSAT Radio

Phase Noise: -95 dBc/Hz @100 KHz Typ. Point-to-Point/Multi-point Radio

No External Resonator Needed Test Equipment & Industrial Controls

Single Supply: +5V @ 220 mA Military End-Use

QFN Leadless SMT Package, 16 mm² Automotive Radar

Related Products



HMC3653LP3BE
Analog Devices, Inc
QFN-12



HMC441LP3E
Analog Devices, Inc
QFN-16



HMC253AQS24

Analog Devices, Inc 24-SSOP (0.154, 3.90mm Width)



HMC948LP3E

Analog Devices, Inc LP3



HMC358MS8GE

Analog Devices, Inc MSOP-8



HMC490

Analog Devices, Inc SMD



HMC453ST89E

Analog Devices, Inc ST89E



HMC618ALP3E

Analog Devices, Inc QFN-16